Workshop ABINIT₀₂

From Total Energies to Curie Temperatures (with ABINIT and VASP)

Steven C. Erwin

Naval Research Laboratory, Washington DC

C. Stephen Hellberg

Jay M. Sullivan (postdoc)

Andre G. Petukhov (sabbatical visitor)

Experimental collaboration: Berry T. Jonker

Ferromagnetic semic

Ferromagnetic semiconductors
From DFT to Heisenberg model
Percolation theory for T_c ABINIT vs. VASP
Self-compensation and T_c





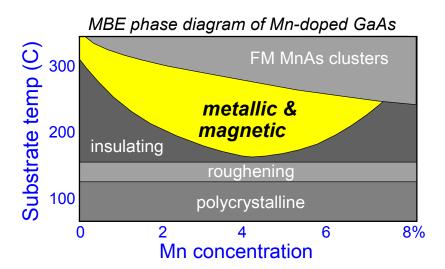
What are ferromagnetic semiconductors?

Prehistory

◆ 1960s: Crystalline FM semiconductors; transition-metal chalcogenides, spinels

Ancient history

◆ 1980s: Dilute Magnetic Semiconductors based on II-VI hosts; Mn-doped CdTe

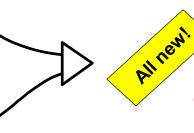


Ferromagnetic DMS's

◆ 1989: Mn-doped InAs (IBM)

◆ 1996: Mn-doped GaAs (Tohoku)

◆ 2000: Mn-doped Ge (NRL)



Non-volatile character plus
Wavefunction engineering

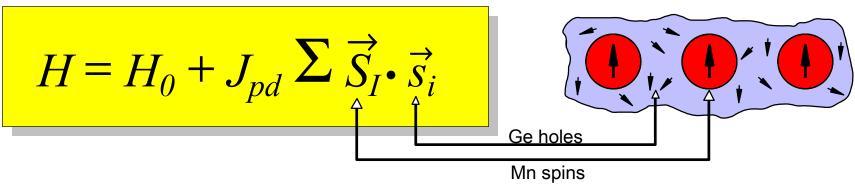
Caveats

- Curie temperatures limited to 120 K
- Limited to *p*-type conduction; *n*-type needed



Ferromagnetism from indirect exchange

The Zener Model for ferromagnetic semiconductors

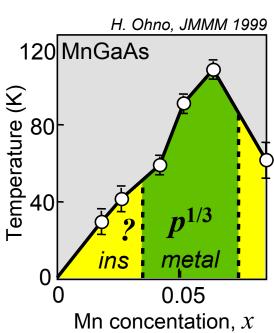


Important points

- ullet Ge(p)-Mn(d) hybridization \Rightarrow J_{pd} > 0 (Antiferromagnetic)
- ◆ Effective interaction between Mn spins is Ferromagnetic
- ♦ Mn provide both spins, x, and holes, p

Mean-field Curie temperature for Mn_xGe_{I-x}

$$T_c \propto J_{pd}^2 x p^{1/3} S(S+1)$$

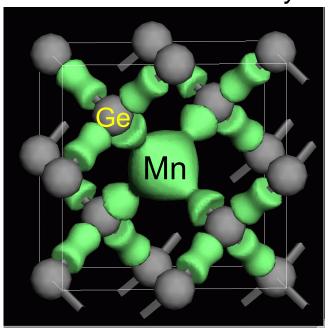




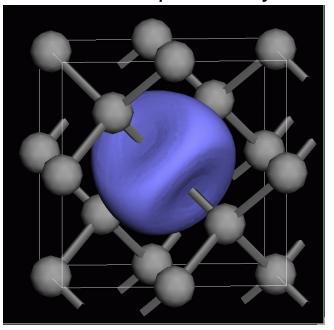
Elemental FM semiconductor, Mn_xGe_{1-x}

Y.D. Park, A. Hanbicki, S.C. Erwin, C.S. Hellberg, J.M. Sullivan, ..., B.T. Jonker, Science 295, 651 (2002)

Valence electron density



Electron spin density



Density Functional Theory

- Mn strongly prefers the substitutional site
- ◆ Surrounding Ge lattice nearly undistorted (< 2% bond strain)
- ◆ Spin density completely localized around Mn



From DFT to the Heisenberg model

Two Mn atoms in Ge supercell

4×2×2 ⇒ 32 atoms, i.e. 6% Mn

DFT total energies

◆ 4 arrangements of Mn along <110>

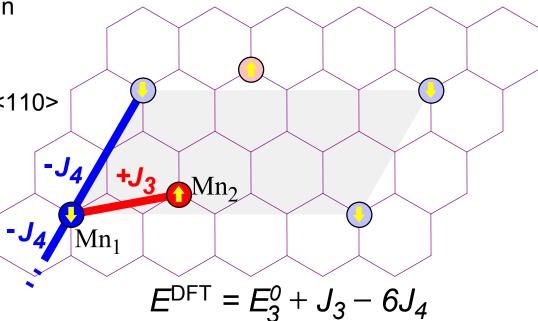
◆ 2 spin configurations

Heisenberg Hamiltonian

$$H = E_{ij}^{0} - \sum_{ij} J_{ij} \vec{S}_{i} \cdot \vec{S}_{j}$$

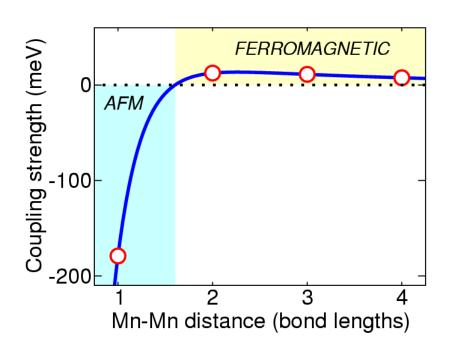
Coupled linear equations

- ♦ \Rightarrow Spin coupling constants, J_n
- ♦ \Rightarrow Chemical energies, E_n^0





Spin coupling constants



DFT coupling constants

J_1	−179.1 meV
J_2	+12.4
J_3	+11.1
J_4	+7.6

Four-parameter fit

$$J(r) = J_{AF} \exp(-r/R_{AF}) + J_{FM} \exp(-r/R_{FM})$$

Competing interactions

$$\Rightarrow$$
 $R_{AF} = 0.5 \text{ Å}, R_{FM} = 5.0 \text{ Å}$

Strong short-range AFM competing with weak long-range FM



Ferromagnetic phase transition

Mean-field theory assumptions

- ◆ Each spin interacts with many
- ◆ Interaction range >> spin radius

MnGe exp'tal concentrations

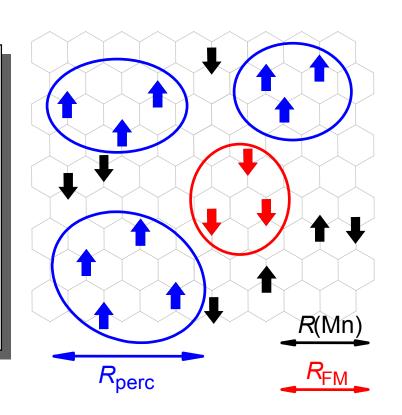
- ◆ Ferromagnetic range R_{FM} = 5.0 Å
- ◆ Average Mn separation comparable:
 R(Mn) ~ 1/x^{1/3} (4.6 Å for x=0.05)

Percolation theory for T_c

Ferromagnetic transition occurs when FM clusters reach $R_{perc} = 1.34 R(Mn)$.

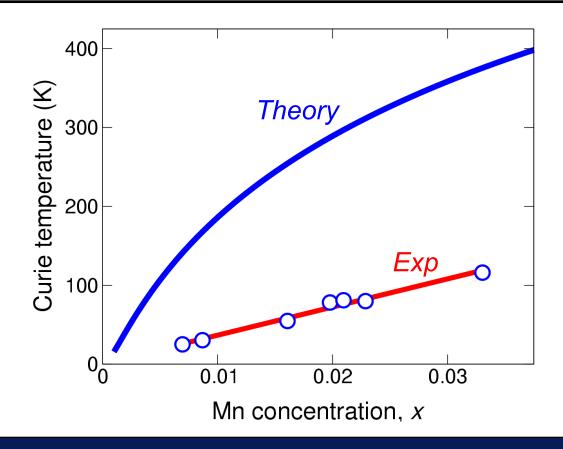
Coupling strength then determines T_c according to:

$$k_B T_c = S(S+1) J(R_{perc})$$





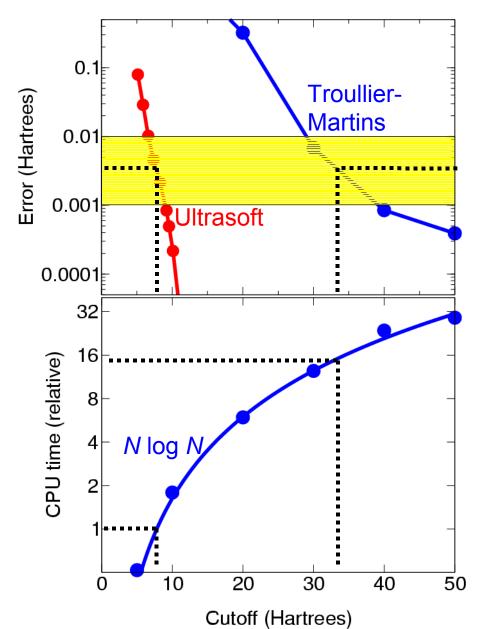
Curie temperature vs. Mn concentration



- 1. Known tendency of LDA to overestimate *J* (by 3-6)
- 2. Strong crystallographic anisotropy of $J(\overrightarrow{R})$
- 3. Hole compensation (in the material, but not in DFT)



ABINIT vs. VASP



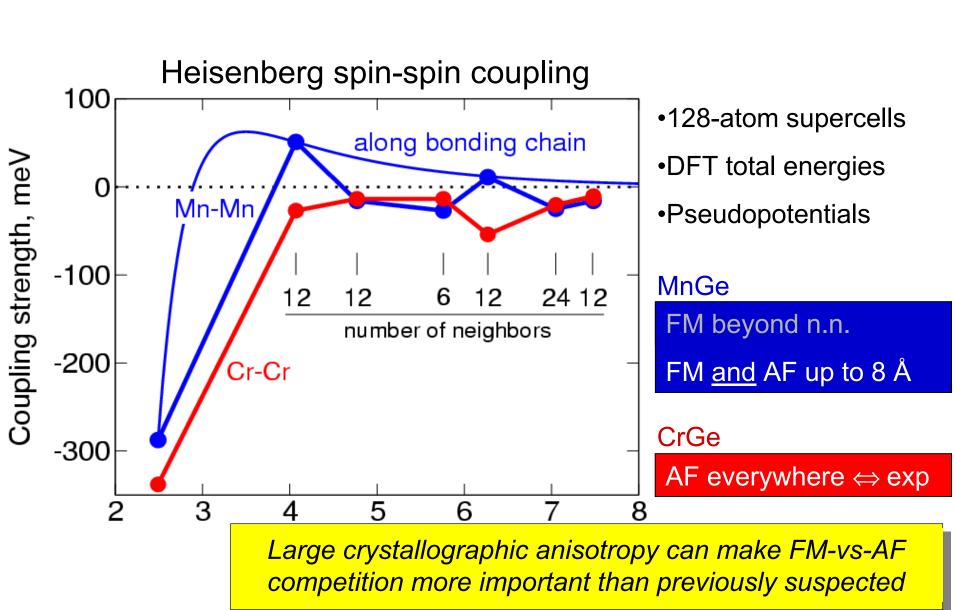
Soft vs. ultrasoft psp's

- •Test: Total energy of Mn₁Ge₁₅
- •ABINIT: Troullier-Martins (*.pspnc)
- •VASP: Ultrasoft (PAW is similar)

- CPU time dominated by FFT
- Ultrasoft advantage > factor 10 (!)



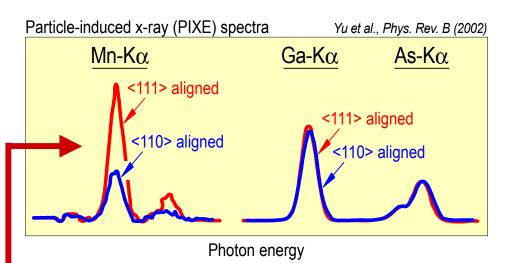
Spin coupling constants, revisited





Compensation by Mn interstitials



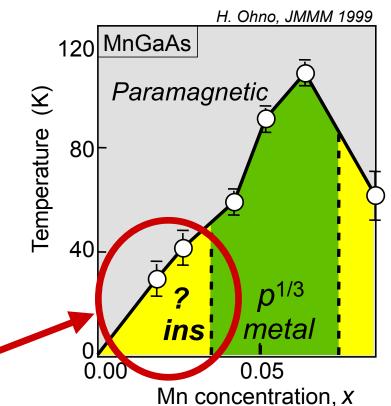


Experimental findings

- Compensation: MnGaAs, MnGe
- Ion channeling ⇒ Interstitial Mn!
- •Exp'l correlation: $T_c \Leftrightarrow p \Leftrightarrow x_{int}$

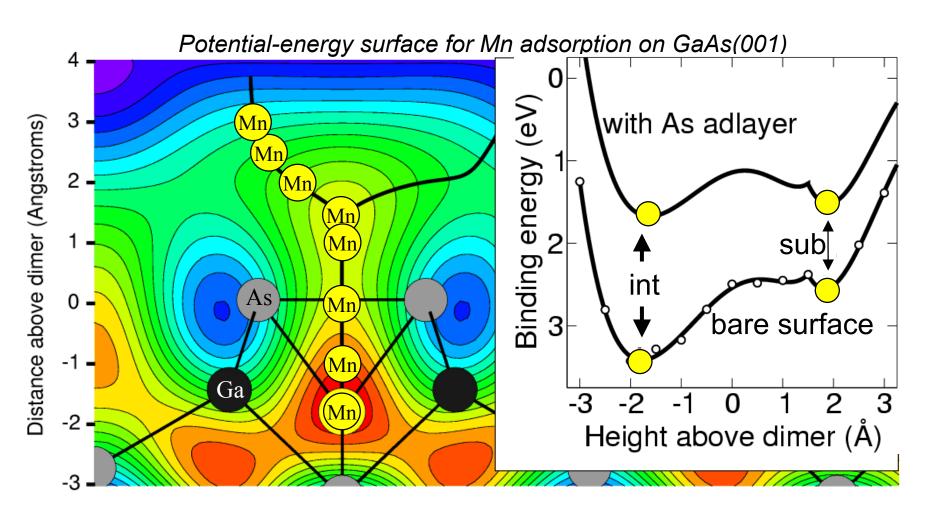
Questions for theory

- How/why are interstitials formed?
- 2. What determines relative abundance of substitutional and interstitial Mn?
- 3. Under what conditions do interstitials compensate?
- 4. What role does compensation play in the ferromagnetism?





Interstitials form during MBE growth



Adsorption at low temperature leads to substitutional and interstitial Mn

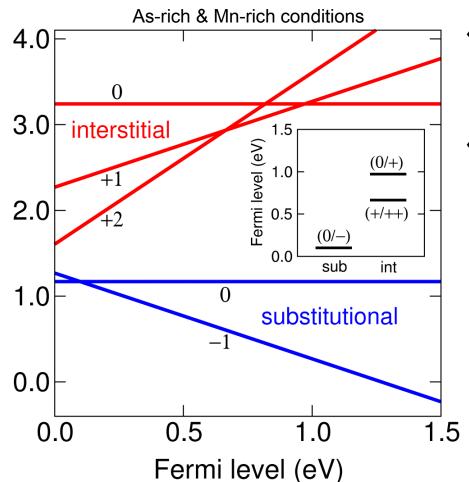


Formation energy (eV)

Electrical activity of Mn impurities

Formation energy

$$E_t [Mn^q] - n_{Ga} \mu_{Ga} - n_{As} \mu_{As} - \mu_{Mn} + qE_F$$



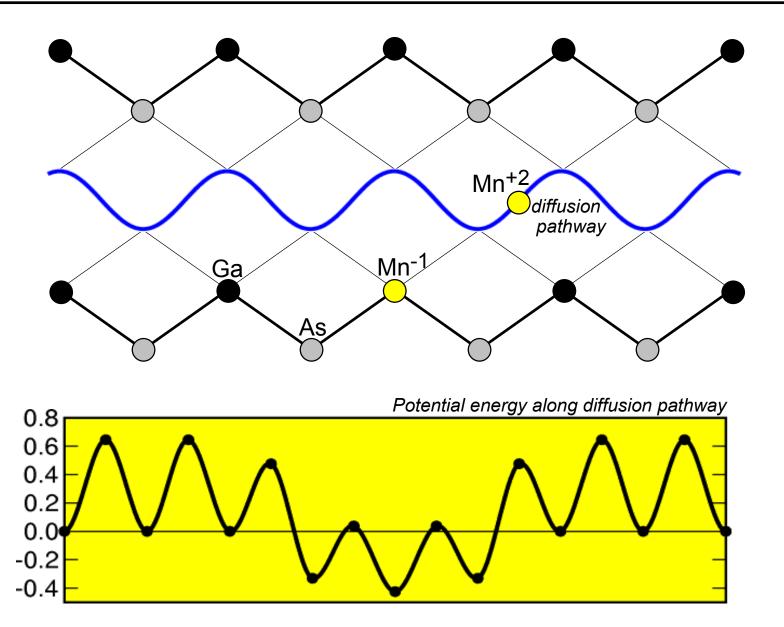
- ◆ Substitutional Mn is a *single acceptor*
 - Ionization energy = 100 meV
 - Exp. ionization energy = 113 meV
- Interstitial Mn is a double donor

Each interstitial compensates two substitutional Mn impurities

If 1/3 of the Mn is interstitial, material is completely compensated



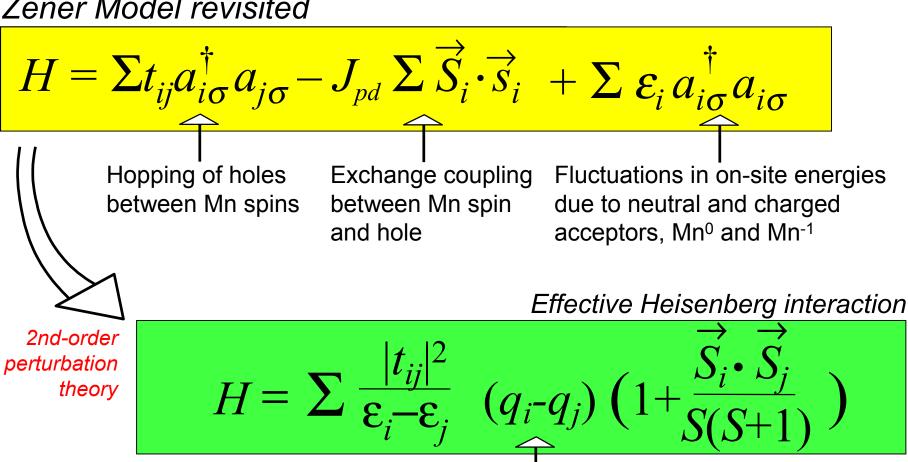
What prevents interstitials from escaping?





Consequences for magnetism

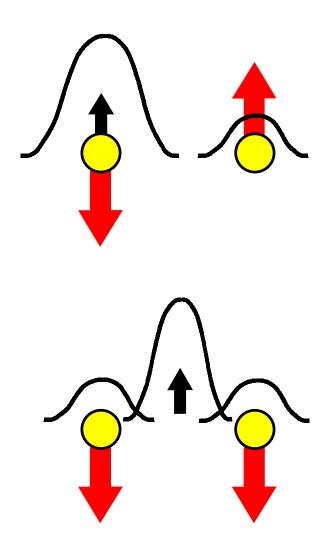
Zener Model revisited



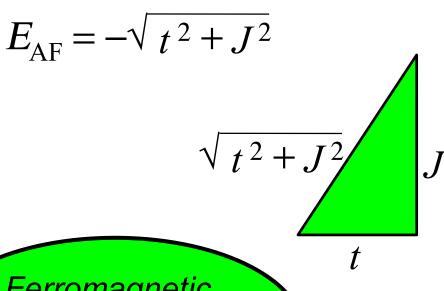
⇒ Ferromagnetic interaction survives only between Mn⁰ and Mn⁻¹!



Toy model: Two Mn atoms sharing one hole



Antiferromagnetic

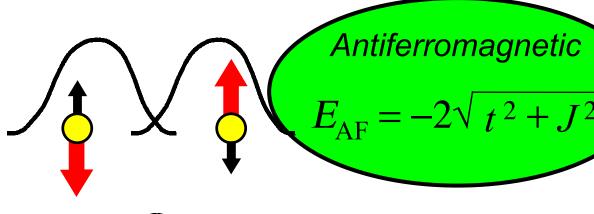


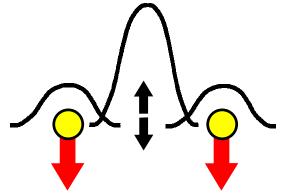
Ferromagnetic

$$E_{\rm FM} = -|t| - |J|$$



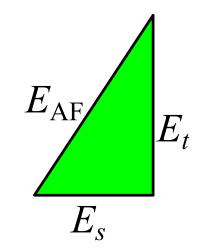
Toy model: Two Mn atoms sharing two holes

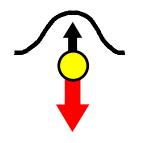


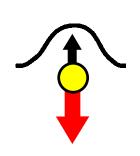


Ferromagnetic singlet

$$E_t = -2 |t|$$





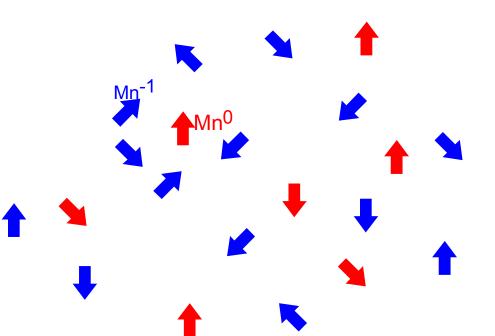


Ferromagnetic triplet

$$E_s = -2 |J|$$

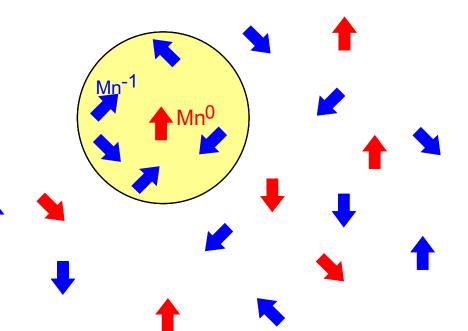


1. Randomly oriented Mn spins, each with charge 0 or -1



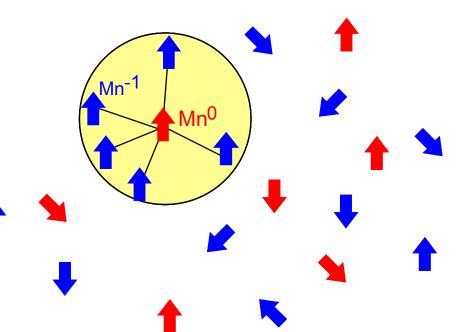


- 1. Randomly oriented Mn spins, each with charge 0 or -1
 - 2. Spins interact if their wavefunctions overlap



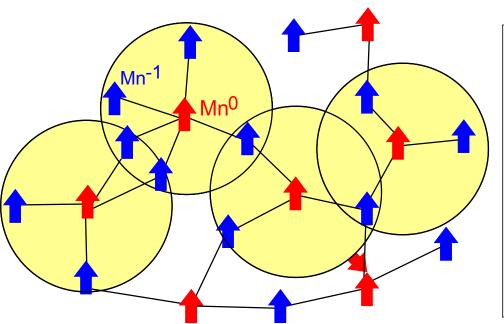


- 1. Randomly oriented Mn spins, each with charge 0 or -1
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 - 3. Spins with opposite charge interact to form ferromagnetic clusters





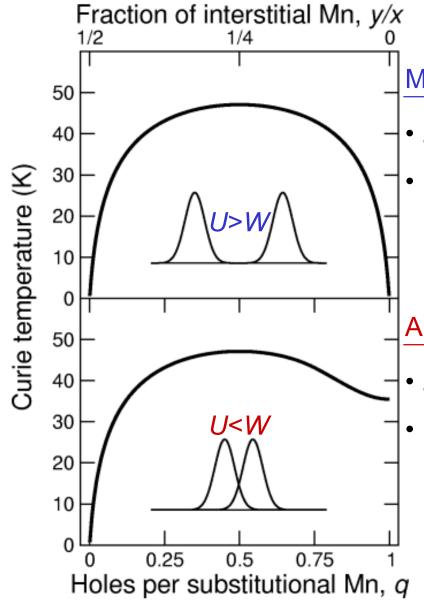
- 1. Randomly oriented Mn spins, each with charge 0 or -1
 - 2. Spins interact if their wavefunctions overlap
 - 3. Spins with opposite charge interact to form ferromagnetic clusters
 - 4. If clusters are larger than the percolation threshold, the entire spin system becomes ferromagnetic



$$R_{\rm perc} \propto \left(\frac{1}{\sqrt{q(1-q)}}\right)^{1/3}$$
 diverges when:
all Mn⁰ (zero comp) all Mn⁻¹ (complete comp)



Curie temperature vs. compensation



Mott-Hubbard insulator

- Zero compensation: $T_c=0$!
- Curie temperature highest for q=0.5

Anderson localization

- Zero compensation: T_c suppressed!
- Curie temperature highest for q=0.5

Below the metal-insulator transition, partial compensation in Mn-doped semiconductors <u>promotes</u> ferromagnetism!



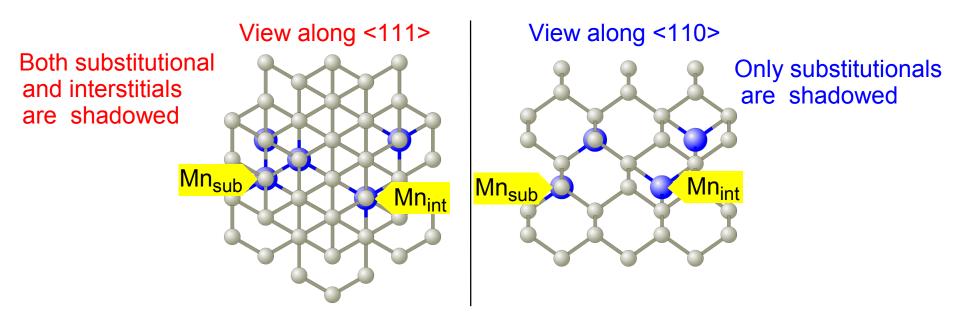
Lessons Learned

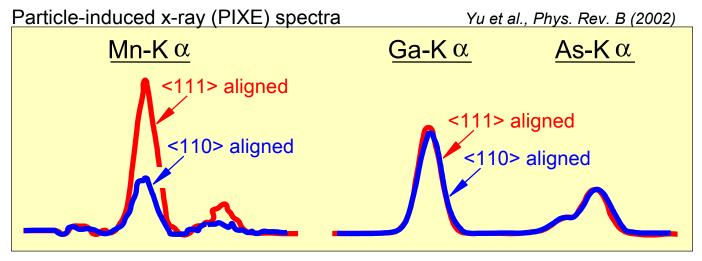
- 1. Convergence is not the same as completeness.
 - 2. Completeness is impossible, but one must try.
 - 3. DFT can't do everything!





Experimental evidence for interstitial Mn

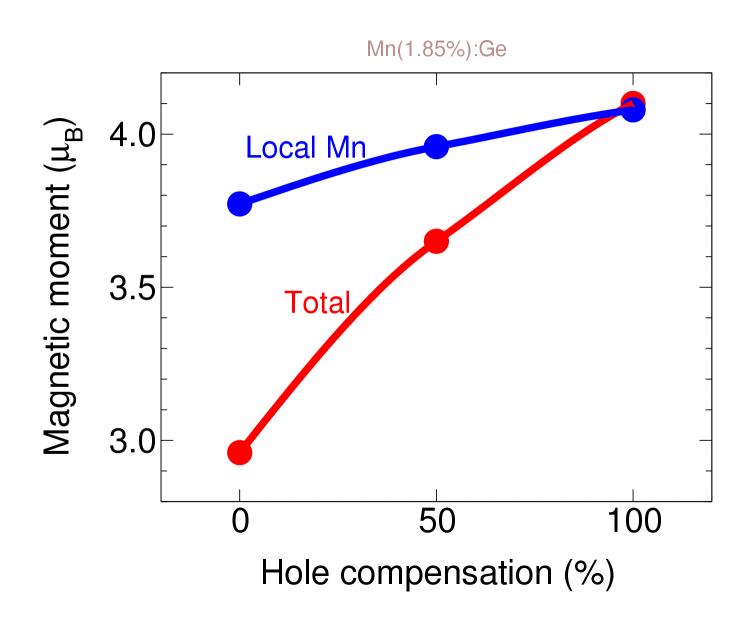




Photon energy



The role of compensation: Mn moment





Compensation suppresses the holes

